

# RA4W1 Group

## High Data throughput sample application

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### Introduction

This document describes the accompanying sample application which controls the Bluetooth® Low Energy communication module. In this document, the module which performs Bluetooth® Low Energy communication is referred to as the BLE module.

### Target Device

RA4W1 Group

### Related Documents

Bluetooth Core Specification (<https://www.bluetooth.com>)

RA4W1 Group User's Manual: Hardware (R01UH0883)

RA Flexible Software Package Documentation

e<sup>2</sup> studio Getting Started Guide (R20UT4204)

EK-RA4W1 – Quick Start Guide (R20QE0015)

EK-RA4W1 User's Manual (R20UT4683)

RA4W1 Group BLE sample application (R01AN5402)

RA4W1 Group Bluetooth Low Energy Profile Developer's Guide (R01AN6459)

### Related Environments

Refer to section 2.1

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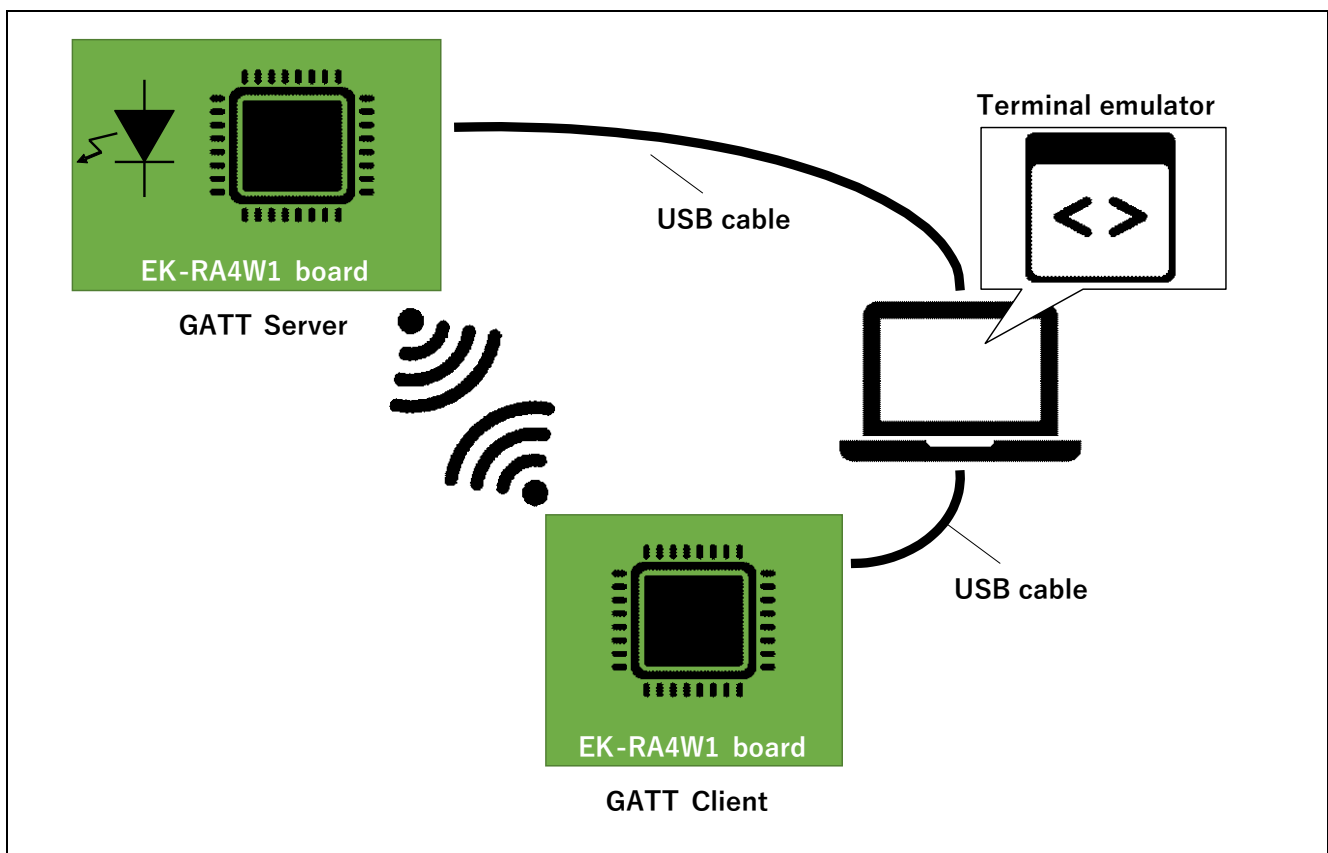
### 1. Overview

Demo projects accompanying this document are shown in Table 1. These projects are provided as BLE sample application using BLE module.

**Table 1. Demo Projects**

Demo Project	Description
RA4W1_Throughput_Server.zip	Server side of high data throughput demo project for BareMetal environment.
RA4W1_Throughput_Client.zip	Client side of high data throughput demo project for BareMetal environment.
RA4W1_Throughput_Server_FreeRTOS.zip	Server side of high data throughput demo project for FreeRTOS environment.
RA4W1_Throughput_Client_FreeRTOS.zip	Client side of high data throughput demo project for FreeRTOS environment.
RA4W1_Throughput_Server_AzureRTOS.zip	Server side of high data throughput demo project for AzureRTOS environment.
RA4W1_Throughput_Client_AzureRTOS.zip	Client side of high data throughput demo project for AzureRTOS environment.

These projects demonstrate high data throughput BLE communication between one pair of EK-RA4W1 by using LE 2M PHY.



**Figure 1. High data throughput demo project operating environment**

### 1.1 BLE application software structure

This sample program has been created by using Flexible Software Package (FSP) BLE Abstraction Driver on rm\_ble\_abs (BLE Module) and QE for BLE. In general, it is necessary to design a profile for exchanging application data and user application itself when developing a Bluetooth Low Energy application. Profile and user application skeleton code can be generated by using QE for BLE. Figure 2 shows software structure of this sample application.

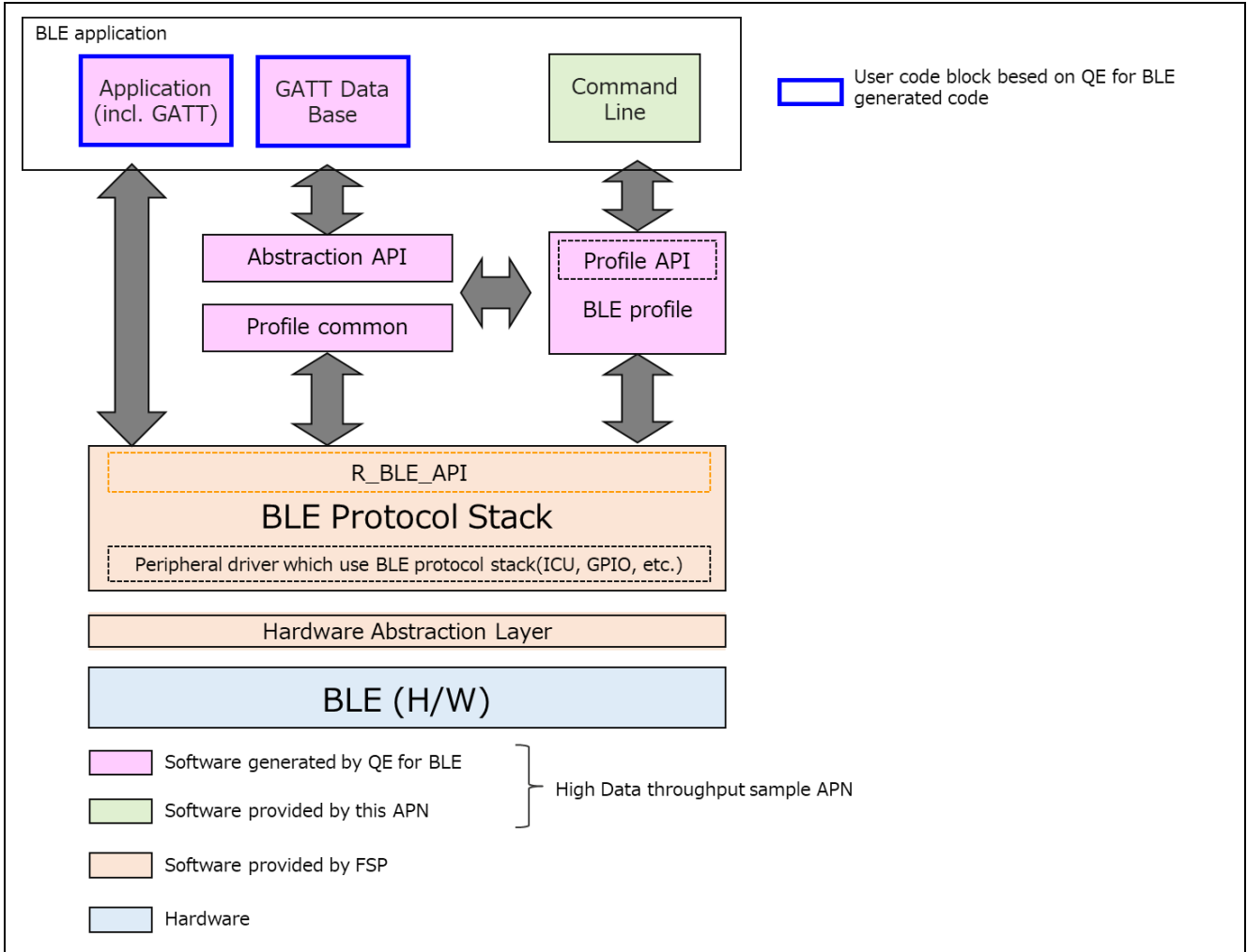


Figure 2. Software structure

## 2. How to use demo project

This chapter describes how to use demo project with this document.

### 2.1 Operating environment

Table 2 shows the hardware requirements for building and debugging BLE software.

**Table 2. Hardware environments**

Hardware	Description
Host PC	Windows® 10 PC with USB interface.
MCU Board	The MCU used must support BLE functions. EK-RA4W1 [RTK7EKA4W1S00000BJ]
On-chip debugging emulators	The EK-RA4W1 has an on-board debugger (J-Link OB), therefore it is not necessary to prepare an emulator.
USB cables	Used to connect to the MCU board. EK-RA4W1: 2 USB A-microB cable

Table 3 shows the environment where the operation of attached sample application was confirmed.

**Table 3. Software environments**

Software	Version	Description
GCC environment	e <sup>2</sup> studio	2022-10 Integrated development environment (IDE) for Renesas devices.
	GCC ARM Embedded	V10.3.1 C/C++ Compiler. (download from e <sup>2</sup> studio installer)
	Renesas Flexible Software Package (FSP)	V4.2.0 Software package for making applications for the RA microcontroller series.
	QE for BLE[RA]	V1.5.0 Generates the source codes (BLE base skeleton program) as a base for the BLE Application and the BLE Profile.  <a href="https://www.renesas.com/qe-ble">https://www.renesas.com/qe-ble</a>
	SEGGER J-Flash Lite	V7.82c Tool for programming the on-chip flash memory of microcontrollers.
Header files		All API calls and their supporting interface definitions located in r_ble_api.h and rm_ble_abs_api.h.
Integer types		It uses ANSI C99 "Exact width integer types". These types are defined in stdint.h.
Endian		Little endian
Terminan emulator		VT-100 compatible

## 2.2 Importing demo project

Refer to *RA4W1 Group BLE sample application (R01AN5402)* about how to import demo projects into e<sup>2</sup>studio. As a result of importation, following file structure will appear in e<sup>2</sup> studio project explorer.

**Table 4. File structure about demo project**

Directory/File structure			Description	
qe_gen	ble	discovery	Service discovery related APIs	
		profile_cmn	Profile common APIs	
		app_main.c	Main code	
		gatt_db.c	GATT Database	
		gatt_db.h	GATT Database	
		r_ble_gapx.c r_ble_gapx.h	GAP APIs (x=s:server, x=c:client)	
		r_ble_gapx.c r_ble_gapx.h	GATT APIs (x=s:server, x=c:client)	
		r_ble_thx.c r_ble_thx.h	Profile APIs (x=s:server, x=c:client)	
ra	fsp	inc	api	BLE API declaration r_ble_api.h rm_ble_abs_api.h
			instances	BLE module structure and macro definitions rm_ble_abs.h
		lib	r_ble	BLE Protocol Stack static library
		src	rm_ble_abs	Abstraction API (RM_BLE_ABS) implementation rm_ble_abs.c
ra_gen	---	---	FSP configuration generated.	
ra_cfg	fsp_cfg	r_ble_cfg.h	Configuration option file	
		rm_ble_abs_cfg.h	Configuration option file	
src	---	hal_entry.c	User code entry point.	
		ble_core_task_entry.c	BLE core task entry point. (FreeRTOS and AzureRTOS only)	
		r_ble_thx_common.h	Throughput custom profile related common macros definitions.	
	app_lib	cli	CLI functionality provided by this demo project	
		cmd	Commands of CLI provided by this project	
		logger	Logger functionality provided by this demo project	

## 2.3 GATT Data Base

GATT data base included in *gatt\_db.c*. Structure of GATT database shown in following table. This demo project implements “Throughput” service as a custom service to achieve high speed communication. GATT data base in this sample program generated by *QE for BLE*. For detail of the custom service, refer to section 3.3.

**Table 5. GATT Data Base**

Service	Attribute handle	Attribute type	Properties	Definition	Note
GAP	0x0001	0x2800	Read	GAP Service Declaration.	
	0x0002	0x2803	Read	Device Name characteristic Declaration.	
	0x0003	0x2A00	Read/Write	Device Name characteristic value.	
	0x0004	0x2803	Read	Appearance characteristic Declaration.	
	0x0005	0x2A01	Read	Appearance characteristic value.	
	0x0006	0x2803	Read	Peripheral Preferred Connection Parameters Characteristic Declaration.	
	0x0007	0x2A04	Read	Peripheral Preferred Connection Parameters characteristic value.	
	0x0008	0x2803	Read	Resolvable Private Address Only Characteristic Declaration.	
	0x0009	0x2AA6	Read	Central Address Resolution characteristic value.	
	0x000A	0x2803	Read	Resolvable Private Address Only Characteristic Declaration.	
	0x000B	0x3AC9	Read	Resolvable Private Address Only characteristic value.	
GATT	0x000C	0x2800	Read	GATT Service Declaration.	
	0x000D	0x2803	Read	Service Changed characteristic Declaration.	
	0x000E	0x2A05	Read	Service Changed characteristic value.	
	0x000F	0x2902	Read	Client Characteristic Configuration descriptor.	
Throughput	0x0010	0x28000	Read	Throughput Service Declaration.	UUID 9CEF3D11-7FAB-49DC-AB89-762C9079FE96
	0x0011	0x2803	Read	Throughput Data1 characteristic Declaration.	UUID 6A66AD-7F11-4B77-B41D-9A8640F7A6A7
	0x0012	See note	Write/Write without response	Throughput Data1 characteristic value.	UUID AF6A66AD-7F11-4B77-B41D-9A8640F7A6A7
	0x0013	0x2803	Read	Throughput Data2 characteristic Declaration.	
	0x0014	See note	Notification /Indication	Throughput Data2 characteristic value.	UUID 6722005A-807A-43D4-9B94-1E6A08EA0478
	0x0015	0x2902	Read/Write	Throughput Data2 client characteristic configuration descriptor.	

## 2.4 Demo project behavior

### 2.4.1 Write demo project to the EK-RA4W1

This section describes how to program this demo project to EK-RA4W1.

1. Turn on terminal #2 of ESW1 on the EK board. And connect ECN1 of the EK board and your PC with a micro-B type USB cable.

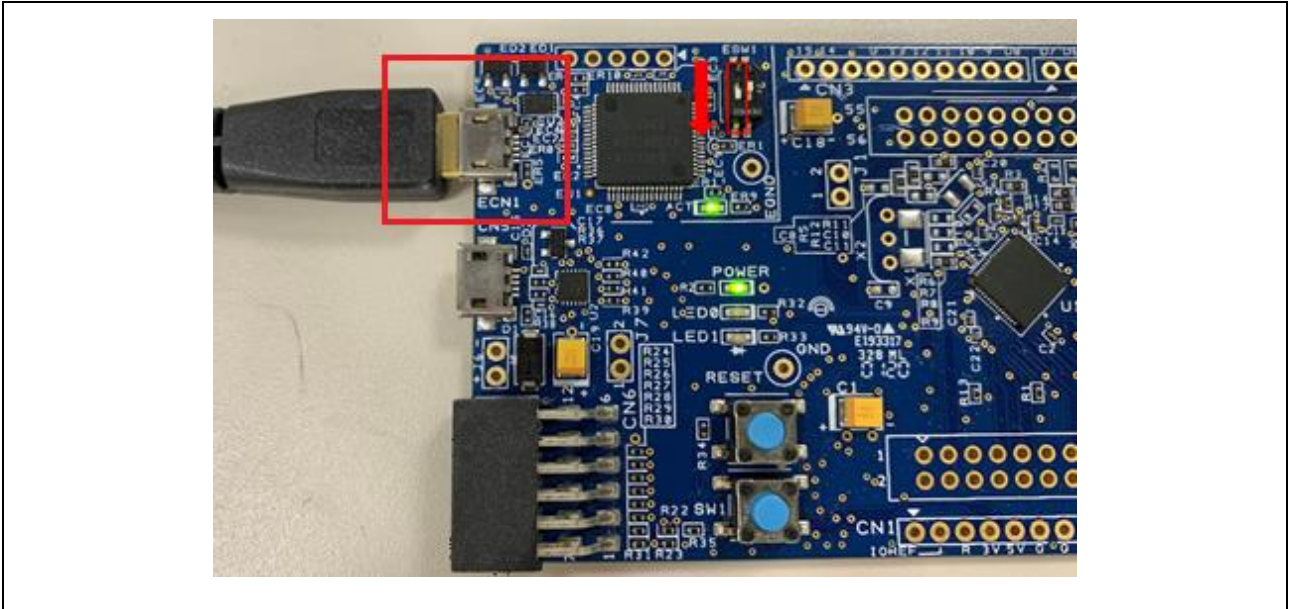


Figure 3. Connecting to the EK-board for program writing

2. Launch J-Flash Lite and click “...” button and select **R7FA4W1AD** as the device. Then click the **OK** button.

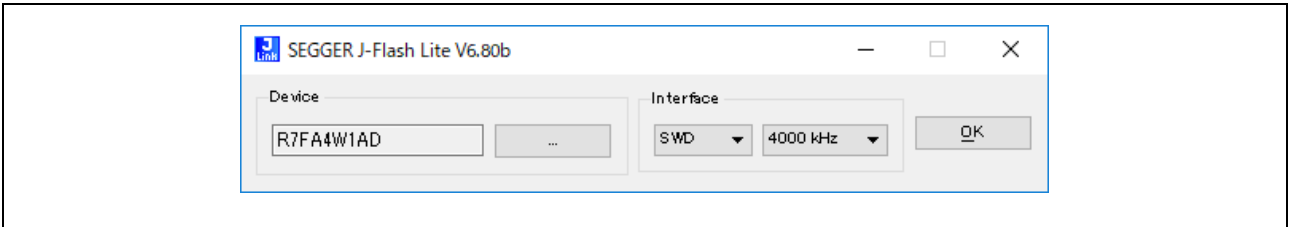


Figure 4. Select Device



- Click "...“button and select \*.srec file obtained by building attached demo project. Then click on the **Program Device** button to write the program to the EK-RA4W1. Program server side of srec file on one side of pair of EK-RA4W1 and client side of srec file on the other side.

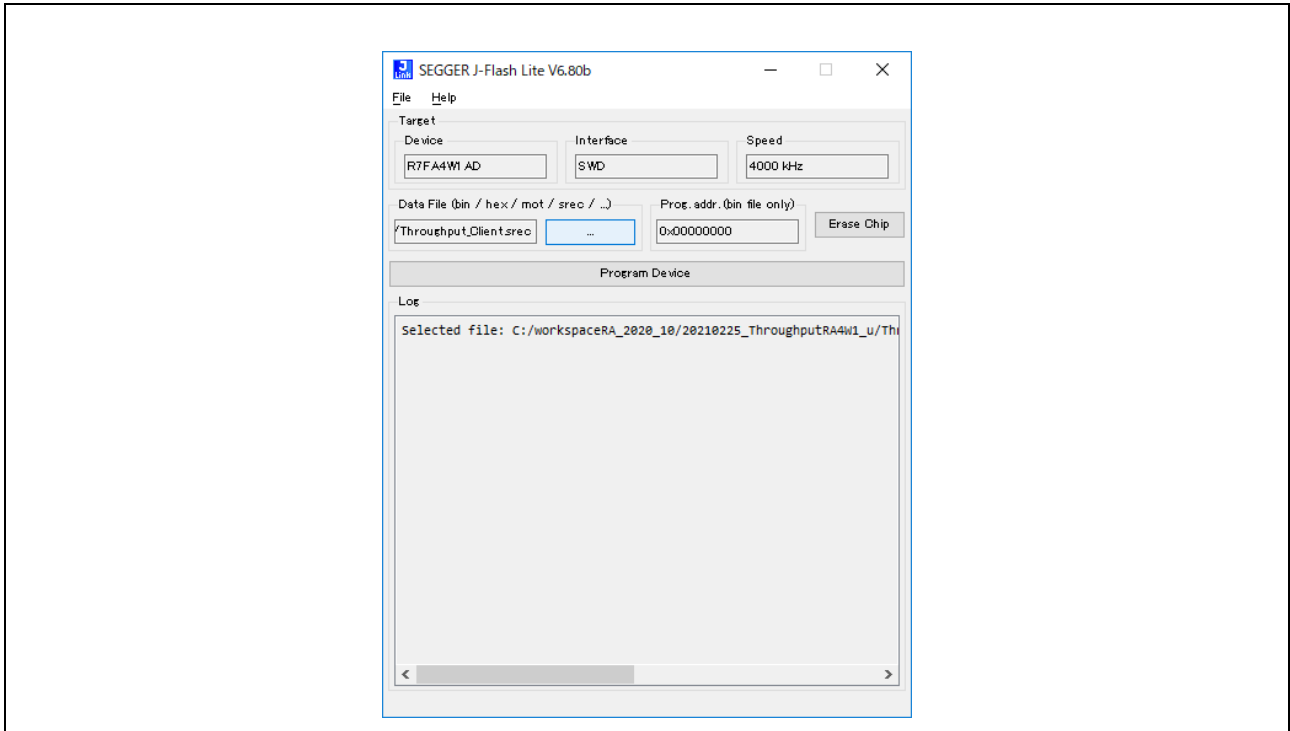


Figure 5. Select srec file

- When the writing of the program completed, "Done" will be appeared in the log.

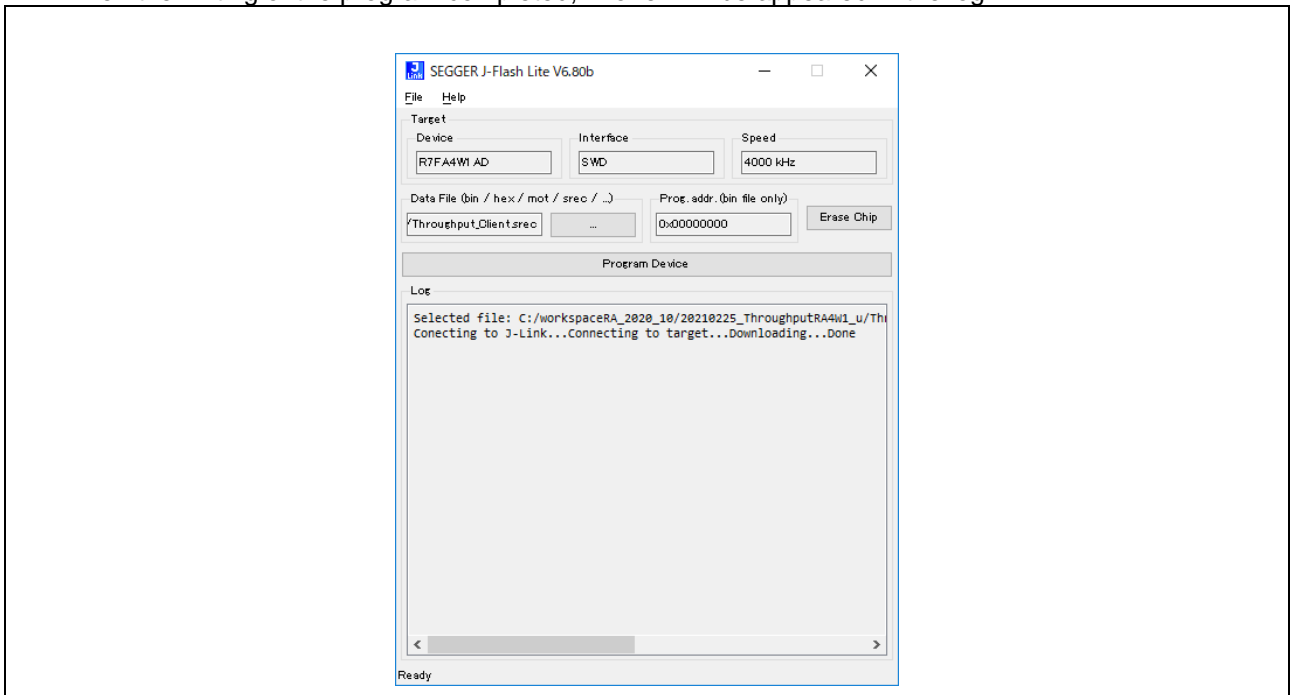


Figure 6. Program completed

- Turn off terminal #2 of ESW1 on the EK board.

### 2.4.2 How to work demo project

This section describes behavior of demo project.

1. Connect CN5 of the EK-RA4W1 and your PC with a micro-B type USB cable.



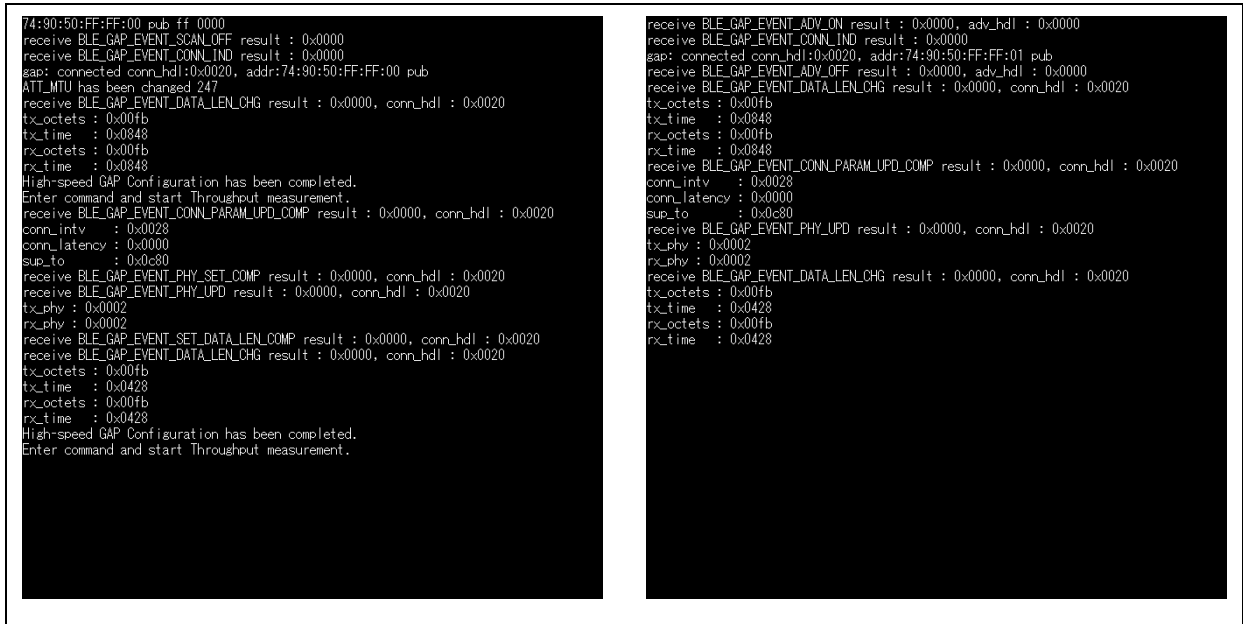
Figure 7. Demo project running

2. Launch VT-100 compatible terminal emulator with following configurations.

Table 6. Setting of the terminal software

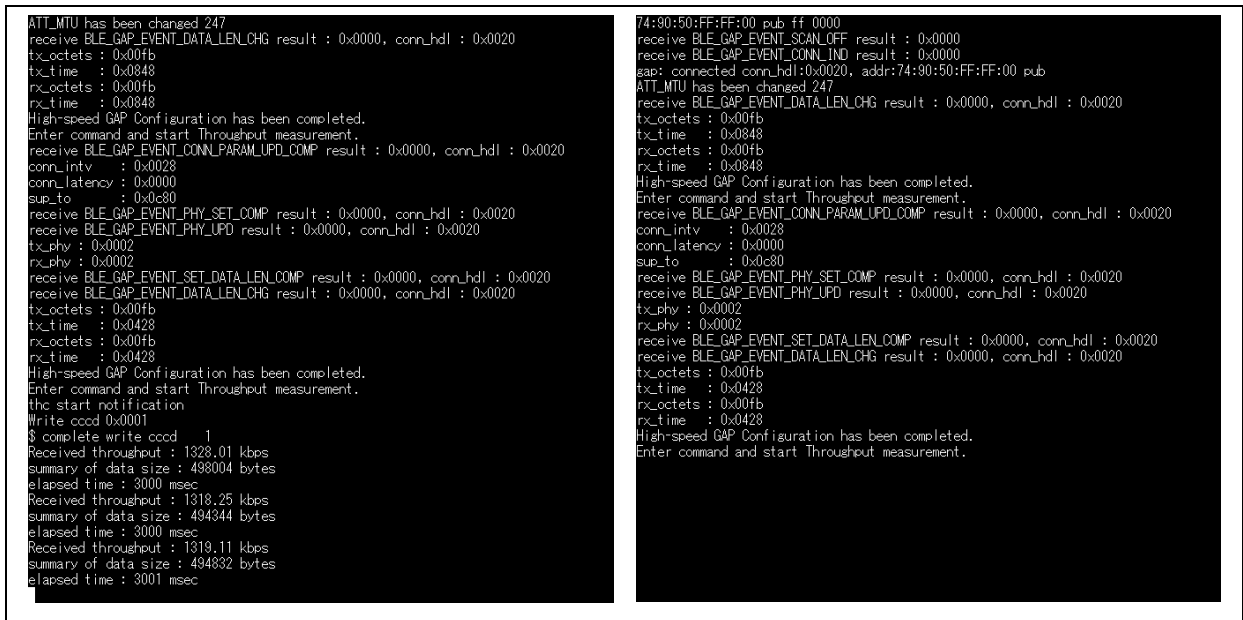
Item	Value
New line (Receive)	LF
New line (Transmit)	CR
Terminal Mode	VT100
Baud rate	115200
Data bits	8bits
Parity	None
Stop bits	1bit
Flow control	None

3. Press "RESET" button on server and client side of EK-RA4W1.
4. Client side will automatically start scan and connect server side. Following characters will appear on terminal emulator after establish connection (Figure 8).



**Figure 8. Console screens ready to start throughput measurement (left : client, right : server)**

5. Put "*thc start notification*" or "*thc start indication*" command on client side of EK-RA4W1. Server side will continuously transmit notification or indication. Client side will show average throughput as following (Figure 9). Put "*Ctrl+C*" on client side if you want to terminate the notification or indication.



**Figure 9. Console screens during throughput measurement (left : client, right : server)**

6. Put “*thc start write\_without\_response*” or “*thc start write*” command on client side of EK-RA4W1. Client side will continuously transmit write without response or write. Server side will show average throughput as following (Figure 10). Put “*Ctrl+C*” on client side if you want to terminate the write without response or write.

```

74:90:50:FF:FF:00 pub ff 0000
receive BLE_GAP_EVENT_SCAN_OFF result : 0x0000
receive BLE_GAP_EVENT_CONN_IND result : 0x0000
gap: connected conn_hdl:0x0020, addr:74:90:50:FF:FF:00 pub
ATT_MTU has been changed 247
receive BLE_GAP_EVENT_DATA_LEN_CHG result : 0x0000, conn_hdl : 0x0020
tx_octets : 0x00fb
tx_time : 0x0848
rx_octets : 0x00fb
rx_time : 0x0848
High-speed GAP Configuration has been completed.
Enter command and start Throughput measurement.
receive BLE_GAP_EVENT_CONN_PARAM_UFD_COMP result : 0x0000, conn_hdl : 0x0020
conn_intv : 0x0028
conn_latency : 0x0000
sup_to : 0x0c80
receive BLE_GAP_EVENT_PHY_SET_COMP result : 0x0000, conn_hdl : 0x0020
receive BLE_GAP_EVENT_PHY_UFD result : 0x0000, conn_hdl : 0x0020
tx_phy : 0x0002
rx_phy : 0x0002
receive BLE_GAP_EVENT_SET_DATA_LEN_COMP result : 0x0000, conn_hdl : 0x0020
receive BLE_GAP_EVENT_DATA_LEN_CHG result : 0x0000, conn_hdl : 0x0020
tx_octets : 0x00fb
tx_time : 0x0428
rx_octets : 0x00fb
rx_time : 0x0428
High-speed GAP Configuration has been completed.
Enter command and start Throughput measurement.
ATT_MTU has been changed 247
receive BLE_GAP_EVENT_DATA_LEN_CHG result : 0x0000, conn_hdl : 0x0020
tx_octets : 0x00fb
tx_time : 0x0848
rx_octets : 0x00fb
rx_time : 0x0848
High-speed GAP Configuration has been completed.
Enter command and start Throughput measurement.
receive BLE_GAP_EVENT_CONN_PARAM_UFD_COMP result : 0x0000, conn_hdl : 0x0020
conn_intv : 0x0028
conn_latency : 0x0000
sup_to : 0x0c80
receive BLE_GAP_EVENT_PHY_SET_COMP result : 0x0000, conn_hdl : 0x0020
receive BLE_GAP_EVENT_PHY_UFD result : 0x0000, conn_hdl : 0x0020
tx_phy : 0x0002
rx_phy : 0x0002
receive BLE_GAP_EVENT_SET_DATA_LEN_COMP result : 0x0000, conn_hdl : 0x0020
receive BLE_GAP_EVENT_DATA_LEN_CHG result : 0x0000, conn_hdl : 0x0020
tx_octets : 0x00fb
tx_time : 0x0428
rx_octets : 0x00fb
rx_time : 0x0428
High-speed GAP Configuration has been completed.
Enter command and start Throughput measurement.
thc start notification
Write cood 0x0001
$ complete write cood 1
Received throughput : 1328.01 kbps
summary of data size : 498004 bytes
elapsed time : 2000 msec
Received throughput : 1318.25 kbps
summary of data size : 494344 bytes
elapsed time : 2000 msec
Received throughput : 1319.11 kbps
summary of data size : 494832 bytes
elapsed time : 2001 msec

```

Figure 10. console screens during throughput measurement (left : client, right : server)

2.4.3 Message Sequence Chart

Figure 11 shows the message sequence chart when notification or indication sent from the server to the client.

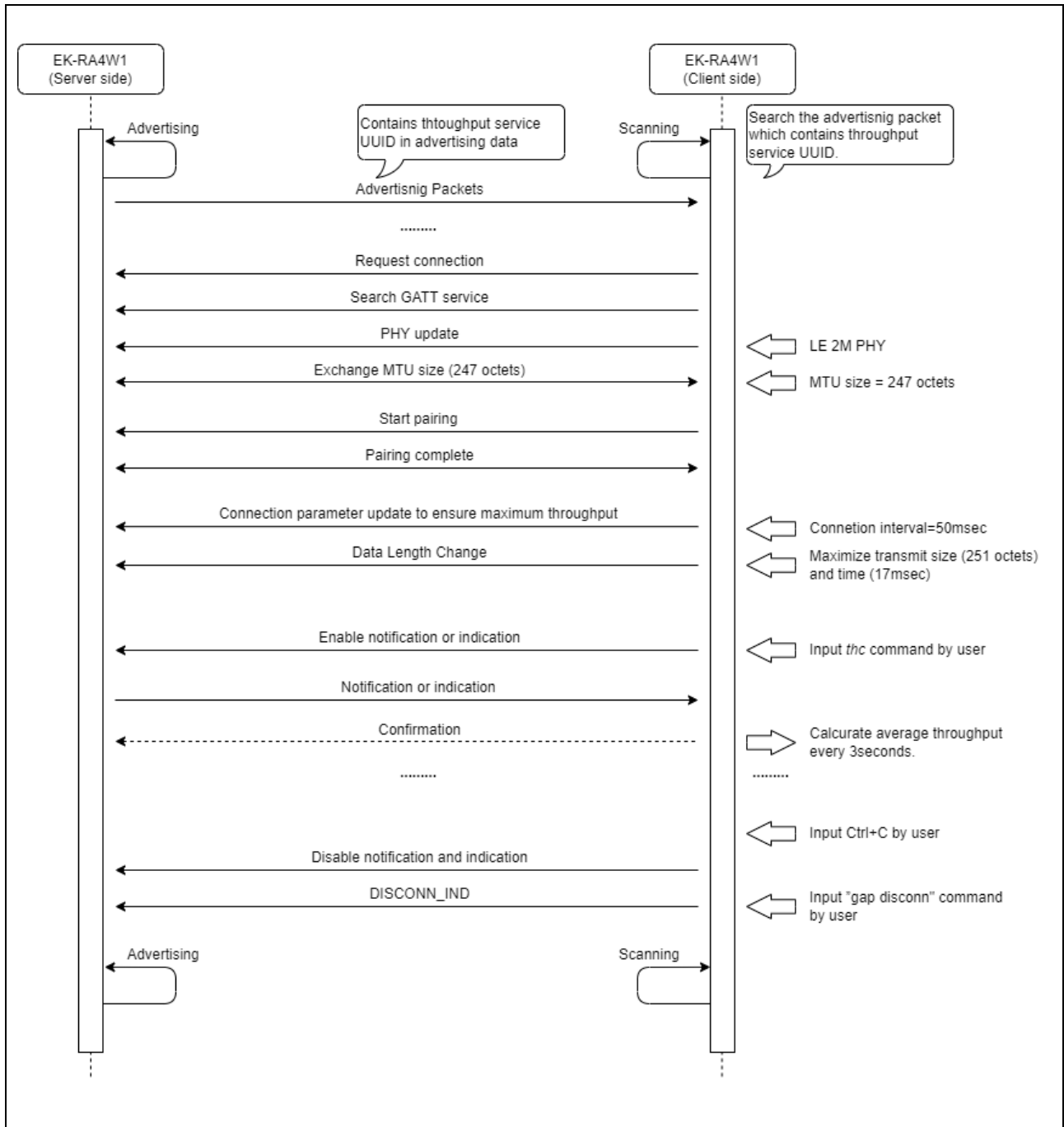


Figure 11. Message Sequence Chart of Notification and Indication

Figure 12 shows the message sequence chart when write or write without response sent from the client to the server.

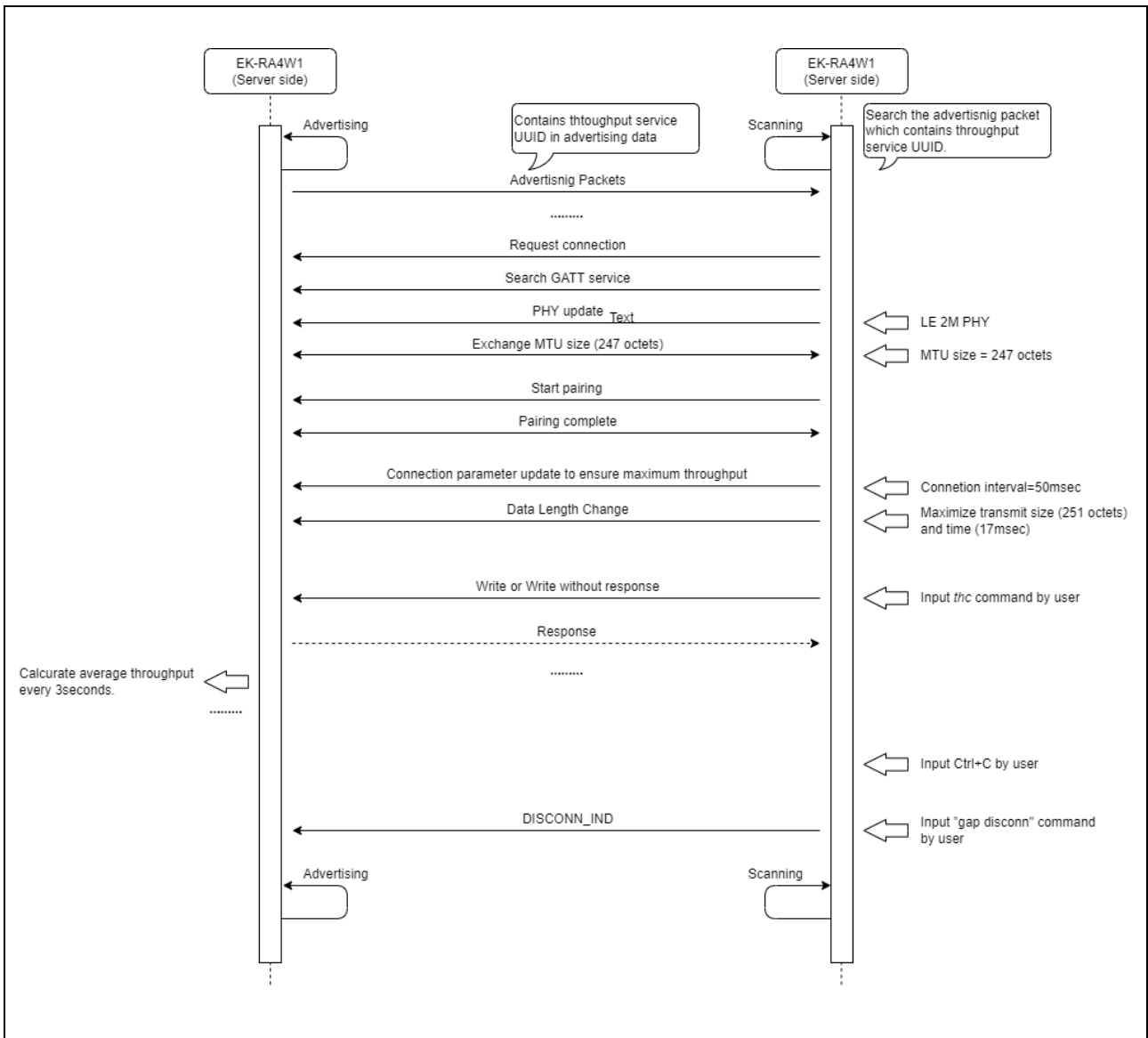


Figure 12. Message Sequence Chart of Write and Write without Response

### 3. Demo project implementation

This chapter describes relationship between the Bluetooth low energy communication mechanism and throughput. For details on communication standards, please refer to the *Bluetooth Core Specification*. Bluetooth Low Energy has three major layers Controller, Host and Host Controller Interface (HCI). Controller and Host are connected by Host Controller Interface (HCI). Application and Host are connected by API (*R\_BLE* and *RM\_BLE\_ABS* API in *BLE Abstraction* in Flexible Software Package) (Figure 13).

In Bluetooth Low Energy, the Link Layer of the controller controls the actual communication path and transmission / reception interval. The operation of this Link Layer is important to achieve highspeed communication. The behavior of the Link Layer is set by the Generic Access Profile (GAP) of the Host Layer.

The Generic Attribute Profile (GATT) of the host layer used to send meaningful application data. The profile determines the application data transmission procedure and the data structure to be transmitted and received. The design of the profile is also important for achieving highspeed communication.

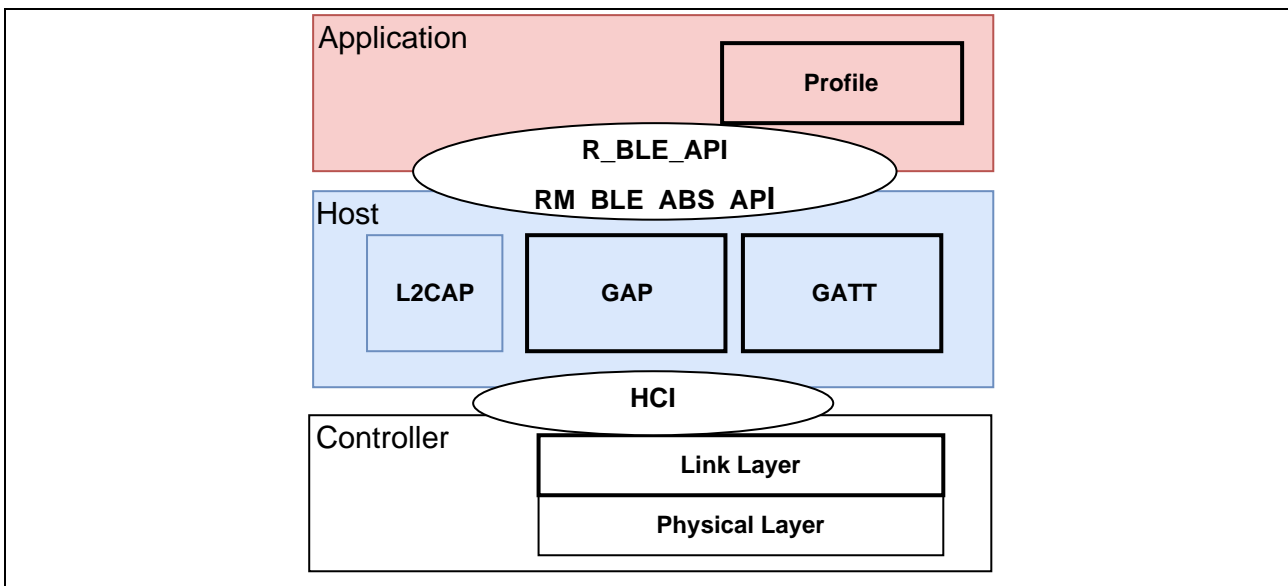


Figure 13. Three major layers in Bluetooth Low Energy

### 3.1 Generic Access Profile (GAP)

Generic Access Profile (GAP) defines the procedure for detecting connectable devices and establishing connections. GAP sets the operation of Link Layer and realizes these procedures.

#### 3.1.1 Device detection and connection establishment

In Bluetooth Low Energy, a connection is established by one device transmitting (advertising) its own device information and the other device performing device detection (scanning) and connection request (initiating). The device that performs scanning and connection request is the central device, and the device that advertises is the peripheral device. Central determines parameters related to connection maintenance such as frequency map and communication interval (connection interval) after connection is established. The GAP will manage the following information.

- Connection Interval
- PHY
- Maximum Packet Length
- Information for Pairing
- etc.



### 3.1.2 Communication after establishing connection

In Bluetooth Low Energy, after the connection is established, the device exchanges radio frames with a connection event that occurs at each connection interval. In the Link Layer, the central is the master and the peripherals are the slaves. Radio frames are transmitted by the master in time with pre-shared connection events. (Figure 14)

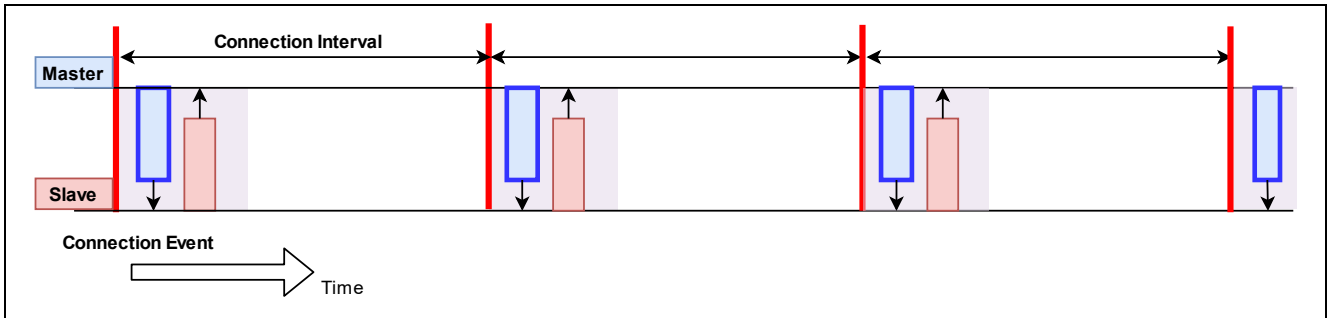


Figure 14. Exchange of connection event and radio frame

The connection is maintained by exchanging radio frames at the connection event. If there is additional data to send to either device, the More Data Bit in the radio frame will be set and the connection event will be extended. The connection event ends when the More Data Bit of each other is no longer set or when an error occurs in the received packet. Once the connection event ends, radio frames are not exchanged until the next connection event (Figure 15). In order to achieve highspeed communication, it is important to communicate using this More Data feature.

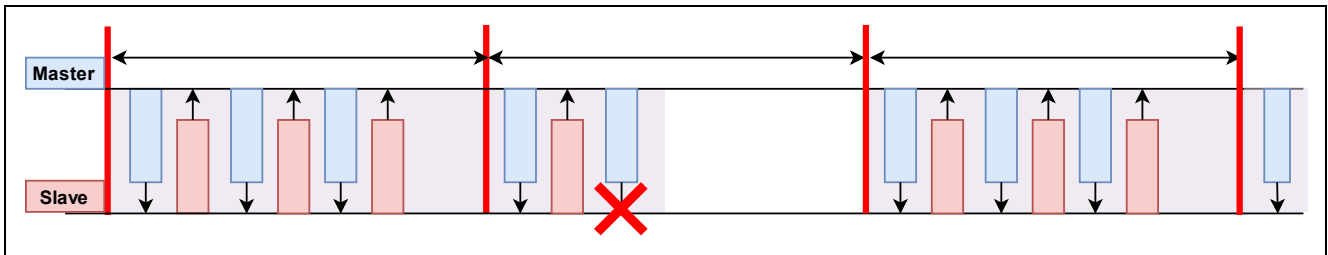


Figure 15. Communication by More Data feature

### 3.1.3 Setting the connection interval

Figure 16 shows Link Layer operation when the connection interval is changed. Even if the connection interval is changed, there is no significant change in throughput as long as the communication by the More Data feature is stable. Note that if the connection interval is extremely short, the throughput will become worse due to the overhead of waiting time for each connection interval.

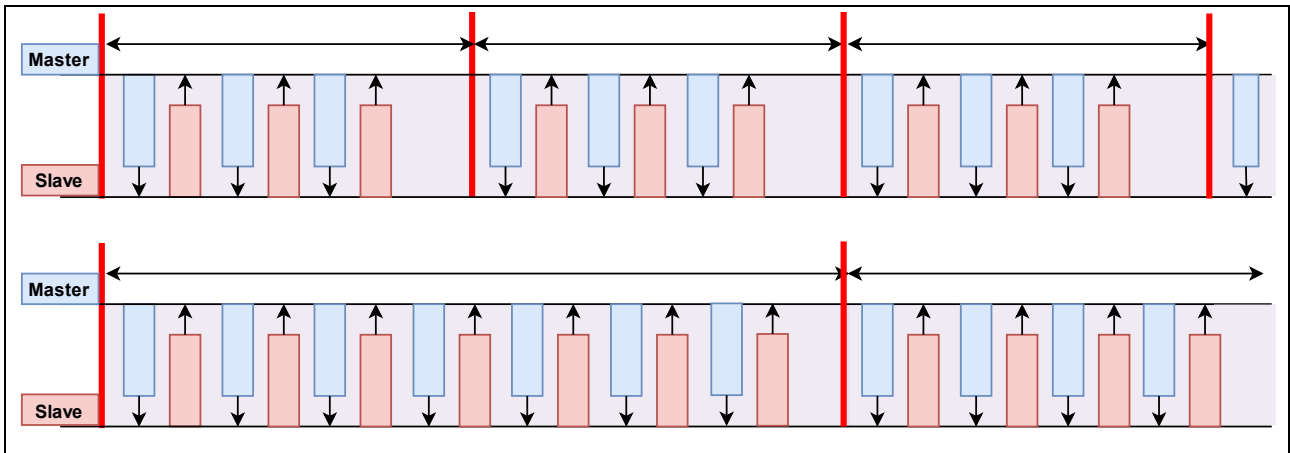


Figure 16. Change in connection interval and number of radio frames

Figure 17 shows the relationship between the connection interval and throughput when using notification case. And assume that the communication environment is good and frame exchange is always successful. The settings of GAP and GATT are PHY: 2M PHY, maximum packet length is 251 bytes, MTU is 247 bytes, and 244 bytes of application data are always notified.

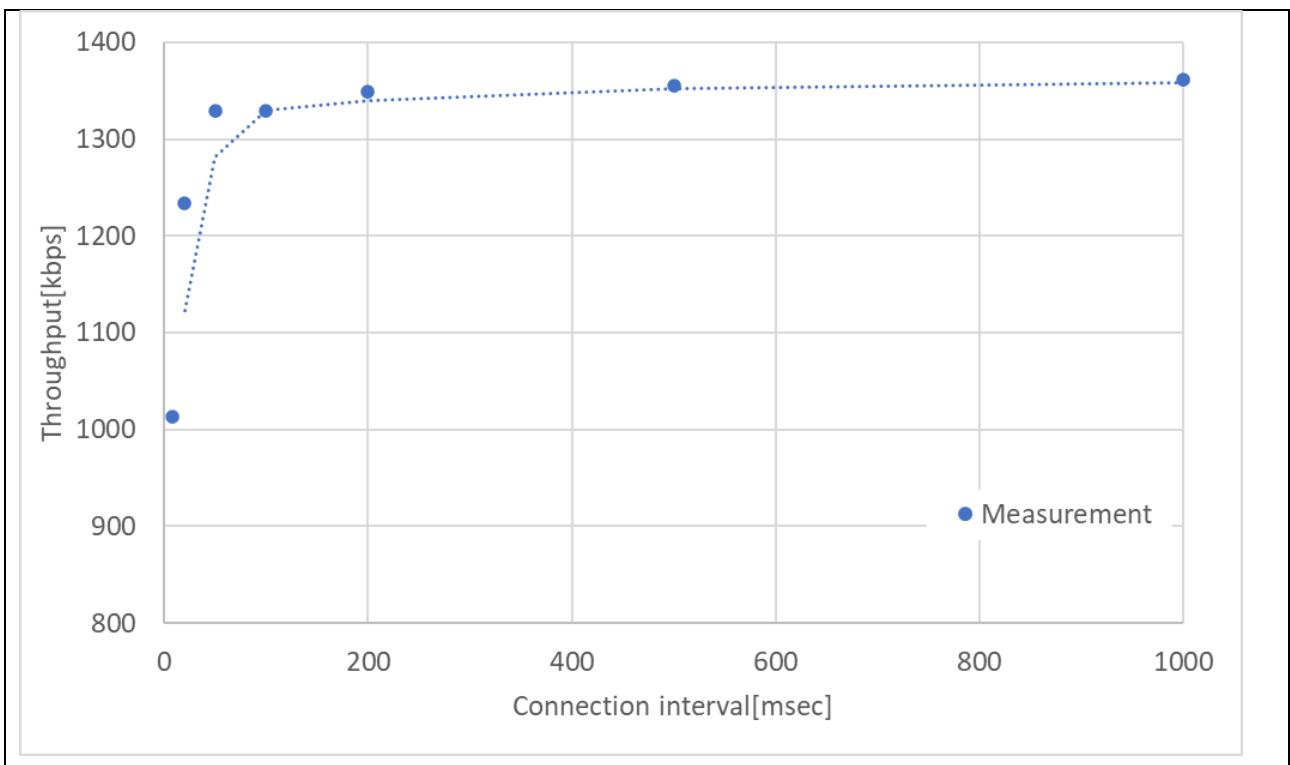


Figure 17. The relationship connection interval and throughput

The throughput per connection interval is calculated from the waiting time  $T_{overhead}$  immediately before the connection event, the minimum transfer time  $T_{frame}$  for the radio frame to make a round trip, and the application data length ( $L_{data}$ ). If the packet length is 251 bytes,  $T_{frame}$  will be about 1.408 msec.

$$Throughput (kbps) = floor\left(\frac{connection\ interval - T_{overhead}}{T_{frame}}\right) * 8 * L_{data} * \frac{1}{connection\ interval}$$

If the communication environment is good, the throughput will not be affected even if the connection interval becomes long. However, if the communication by using the More Data bit is interrupted due to a communication error (e.g. interference), the effect of the connection interval on the throughput will be large (Figure 18). When a communication error occurs, each device waits until the next connection event. Therefore, throughput decreases as the connection interval increases.

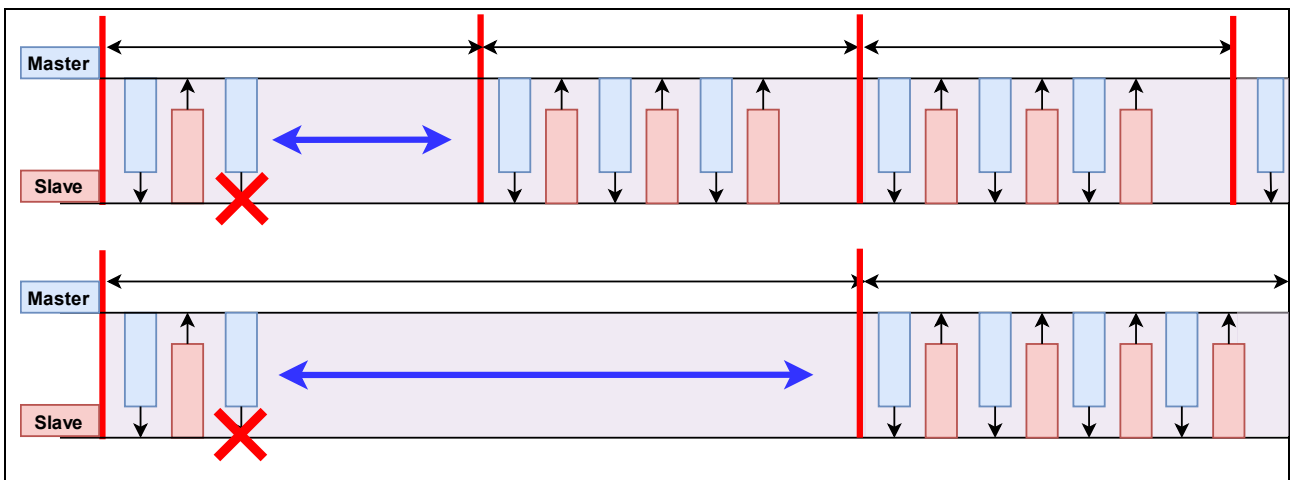
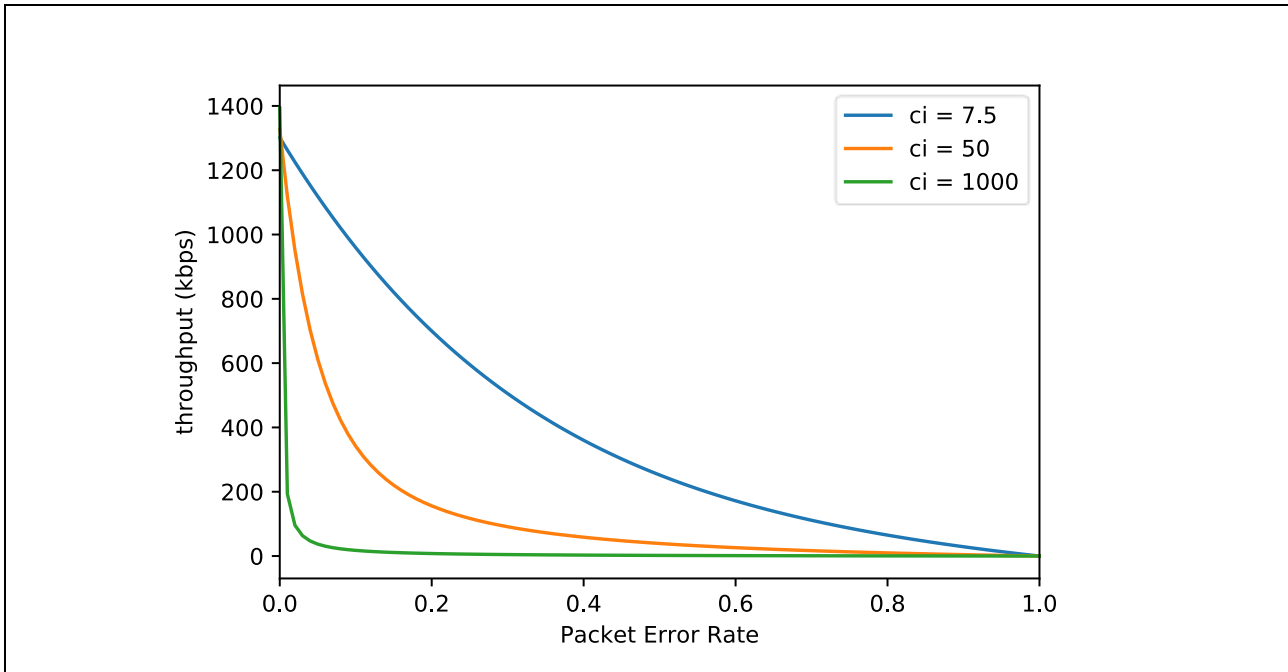


Figure 18 Connection interval and throughput when communication error occurs

Figure 19 shows the relationship between connection interval, probability of frame exchange failure, and throughput. GAP settings are PHY: 2M PHY, maximum packet length 251 bytes, MTU 247 bytes, and the value when 244 bytes of application data are always notified. The expected value of throughput per connection interval is plotted.



**Figure 19. Relationship between frame exchange failure probability and throughput**

To change the connection interval, execute the "gap conn\_cfg update" command on terminal emulator. For details about the command, refer to *RA4W1 Group BLE sample application(R01AN5402)*. *R\_BLE\_GAP\_UpdConn* API can also be used to change connection interval. For details about the API, refer to "*RA Flexible Software Package Documentation*".

### 3.1.4 Setting the PHY

Figure 20 shows Link Layer operation when the physical layer (PHY) settings are changed. When the physical layer PHY is changed, the radio frame occupation time will be changed. If the data length is the same, the occupation time in 2M PHY is about half of that in 1M PHY. If the occupation time of one frame in the air is short, the number of packets transmitted / received per unit time increases, and the throughput improves.

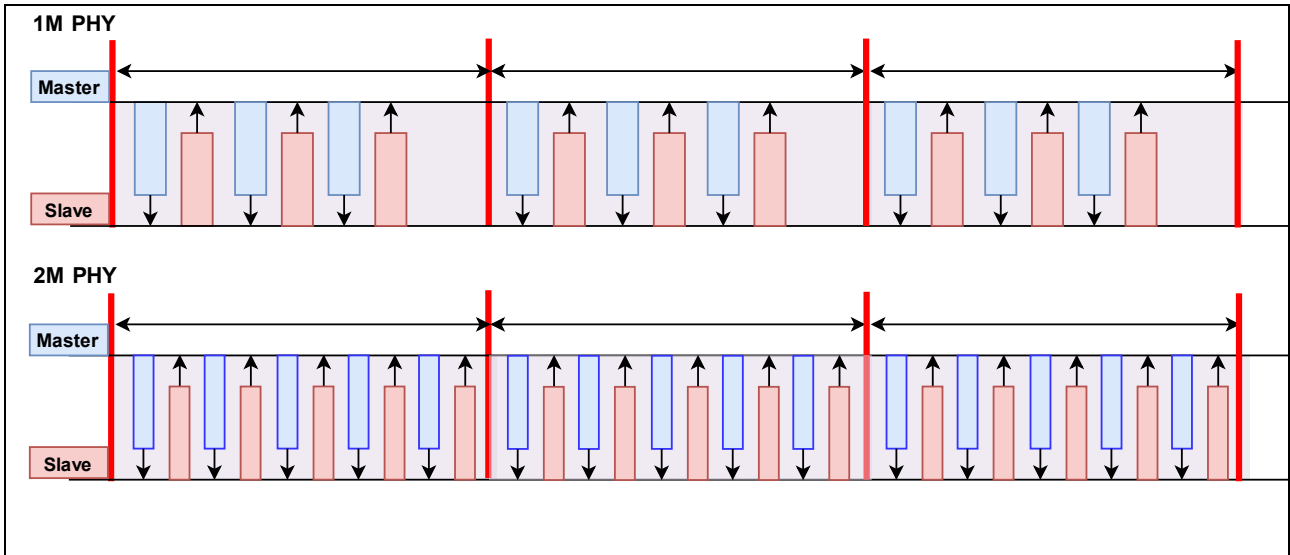


Figure 20. Schematic diagram when using 2M PHY

To change the PHY, execute the “*gap conn\_cfg phy*” command on terminal emulator. For details about the command, refer to *RA4W1 Group BLE sample application (R01AN5402)*. *R\_BLE\_GAP\_SetPhy* API can also be used to change PHY. For details about the API, refer to “*RA Flexible Software Package Documentation*”.

### 3.1.5 Setting the Maximum packet length

Figure 21 shows Link Layer operation when the maximum packet length is set to long. The application information can be transmitted efficiently by minimizing the header information of the radio frame and the transmission / reception interval.

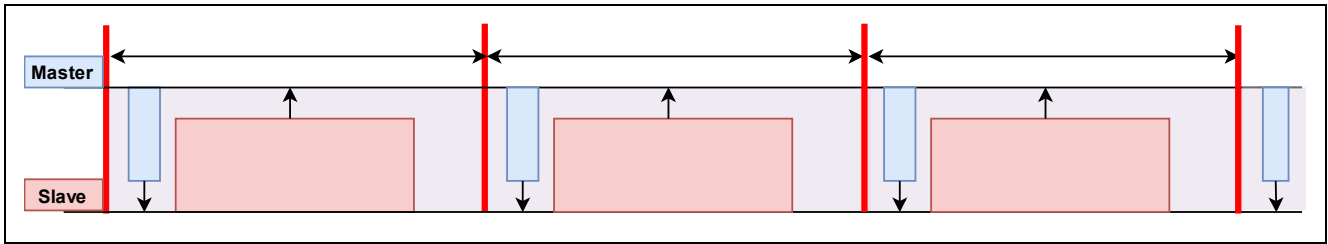
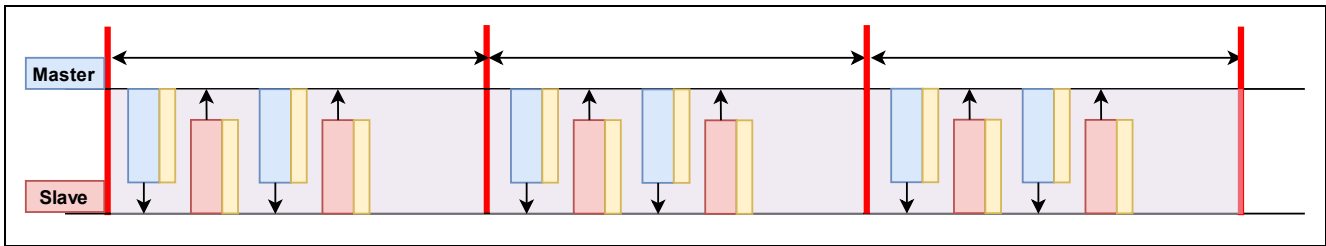


Figure 21. Schematic diagram of Link Layer when changing packet length

To change the Maximum packet length, execute the “`gap conn_cfg data_len`” command on terminal emulator. For details about the command, refer to *RA4W1 Group BLE sample application (R01AN5402)*. `R_BLE_GAP_SetDataLen` API can also be used to change maximum packet length. For details about the API, refer to “*RA Flexible Software Package Documentation*”.

**3.1.6 Setting the encryption of communication**

Figure 22 shows Link Layer operation when communication is encrypted. Through encryption, the data for checking packet integrity (4 bytes) is carried in the radio frame, which may reduce the throughput.

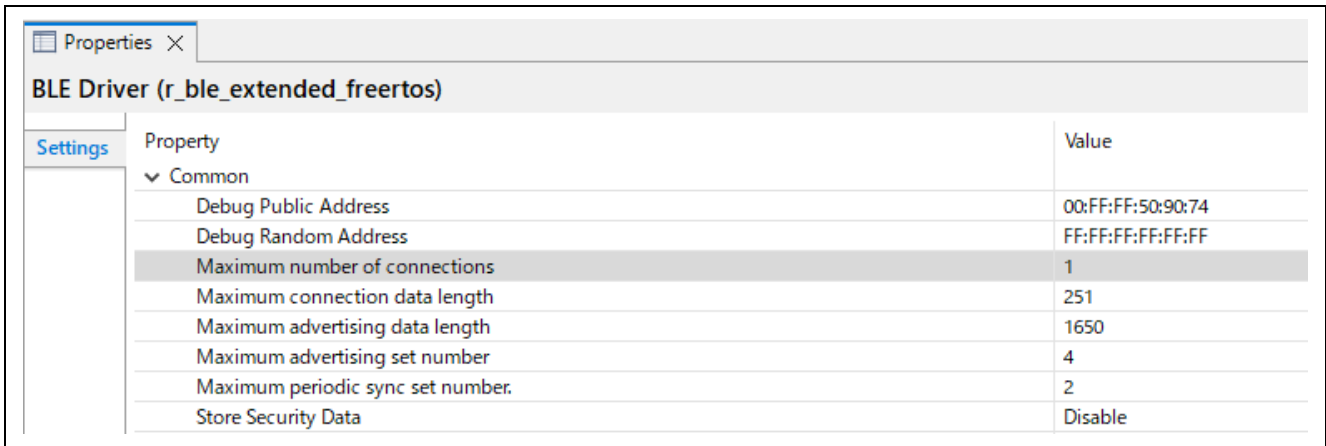


**Figure 22. Schematic diagram of Link Layer in encrypted communication**

To encrypt communication, execute the “*gap auth start*” command on terminal emulator. For details about the command, refer to *RA4W1 Group BLE sample application (R01AN5402)*. *RM\_BLE\_ABS\_StartAuthentication* API can also be used to encrypt communication. For details about the API, refer to “*RA Flexible Software Package Documentation*”. Always encrypt in sample project attached to this document.

### 3.1.7 FSP configuration

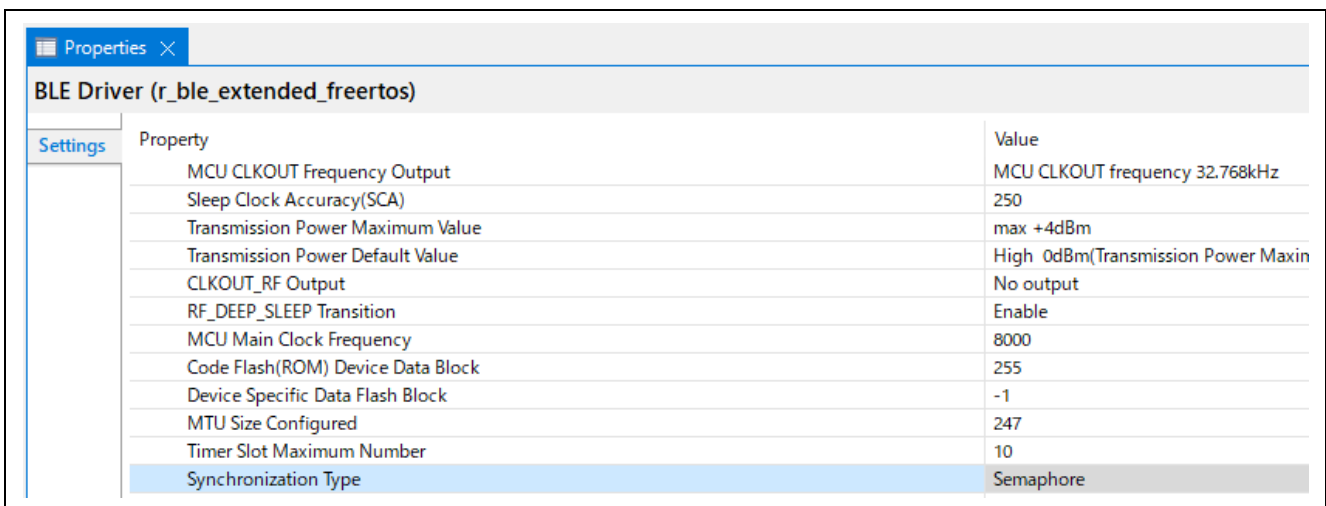
It is necessary for obtain high throughput to configure *Maximum number of connections* property as 1. The property is in *BLE Driver* FSP module



Property	Value
Debug Public Address	00:FF:FF:50:90:74
Debug Random Address	FF:FF:FF:FF:FF:FF
Maximum number of connections	1
Maximum connection data length	251
Maximum advertising data length	1650
Maximum advertising set number	4
Maximum periodic sync set number.	2
Store Security Data	Disable

Figure 23. Maximum number of connections property

And in FreeRTOS environment, it is recommended to set *Synchronization type* property to *Semaphore*. The property is in *BLE Driver* FSP module.



Property	Value
MCU CLKOUT Frequency Output	MCU CLKOUT frequency 32.768kHz
Sleep Clock Accuracy(SCA)	250
Transmission Power Maximum Value	max +4dBm
Transmission Power Default Value	High 0dBm(Transmission Power Maxim
CLKOUT_RF Output	No output
RF_DEEP_SLEEP Transition	Enable
MCU Main Clock Frequency	8000
Code Flash(ROM) Device Data Block	255
Device Specific Data Flash Block	-1
MTU Size Configured	247
Timer Slot Maximum Number	10
Synchronization Type	Semaphore

Figure 24. Maximum number of connections property

Please also refer to *RA4W1 Group BLE sample application* (R01AN5402) section 4.1 about the other properties.



### 3.2 Generic Attribute Profile (GATT)

GATT determines the communication procedure for application data (e.g. sensor data). GATT implements a client-server architecture over the communication path established by GAP. The client reads / writes data from / to the GATT database held by the server using a predetermined procedure. The server returns a response to the client. And it is also possible for the server to notify to the client (Figure 25).

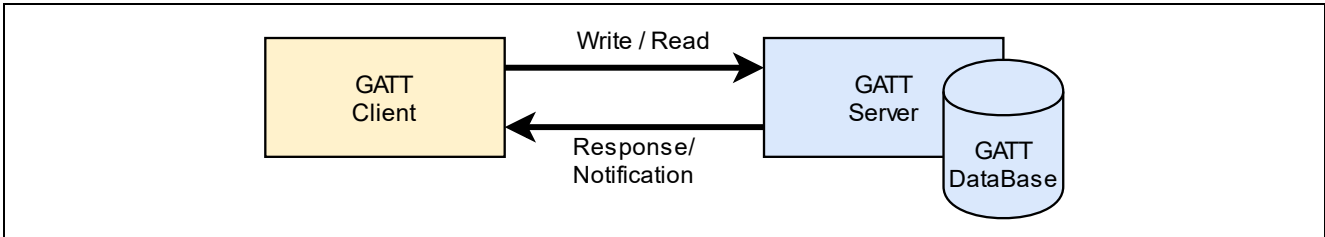


Figure 25. GATT architecture

The feature of an application is called a "service", and the data required for that feature is called a "characteristic." A "profile" is a set of services required to realize an application and defines the communication specifications of the application.

Figure 26 shows the relationship between profile, service, and characteristic when using a thermometer as an example. The features of the thermometer application are temperature measurement and device information. Features and data are kept on the GATT database as services and characteristics.

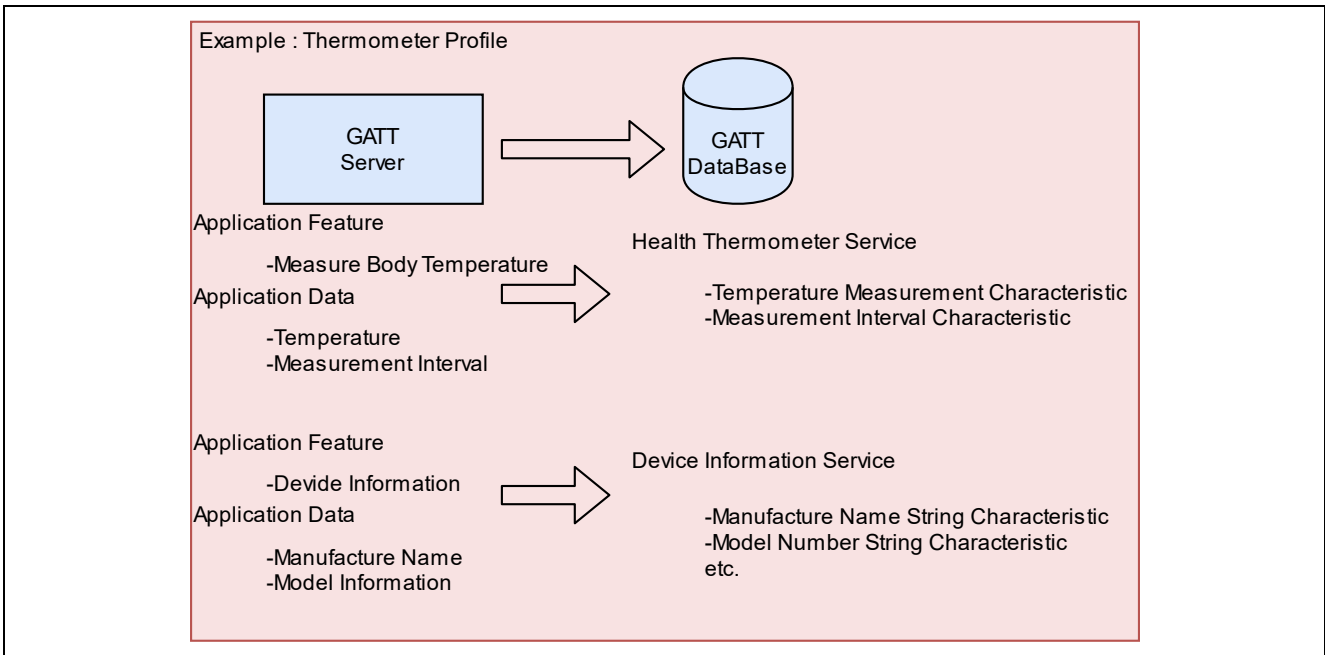


Figure 26. Application Data and GATT database

When performing GATT communication, it is necessary to share service and characteristic information between client and server. The service and characteristic information is store in database of server. Immediately after establishing a connection, the client does not have service information for the server. The client queries the server for a particular service by using service discovery procedure (Figure 27). The client obtains information about the particular service and handle of the service from the GATT database held by server. The client will use the handle to read and write to the GATT database.

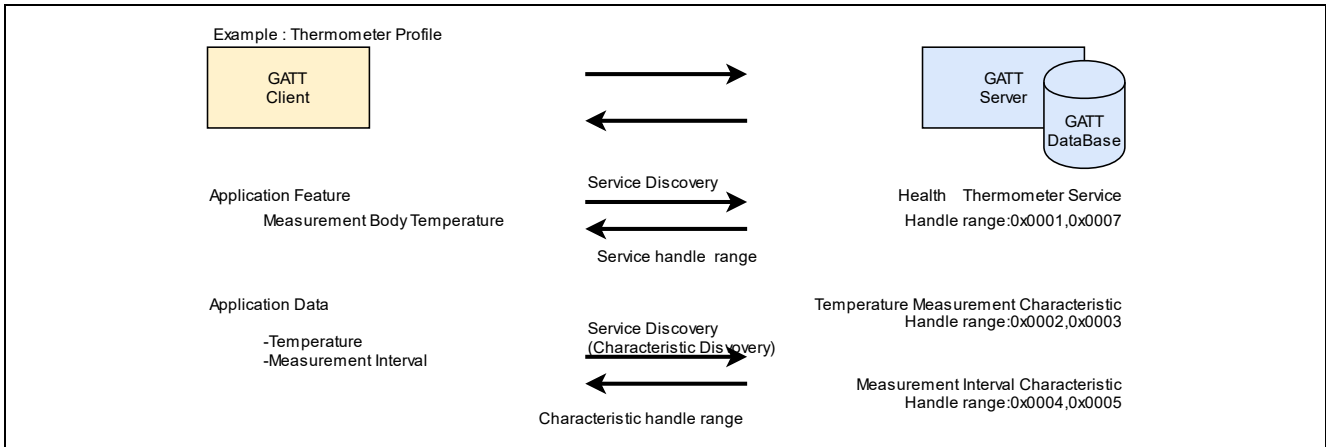


Figure 27. Service discovery operation

Characteristic defines the data, its structure, and the procedure for exchanging data between the client and server. The characteristic descriptor defines additional options for the data exchange procedure.

Table 7 summarizes the typical data exchange procedures. These procedures are categorized by the direction of data transmission and the presence or absence of a response. A procedure that requires a response cannot perform the same procedure before receiving a response.

Table 7. Typical communication procedure of GATT communication

Procedure name	Operation	Direction to transmit	Response required
Read	Read	From client to server	Yes
Write	Write	From client to server	Yes
Write Without Response	Write	From client to server	No
Indication	Notify	From server to client	Yes
Notification	Notify	From server to client	No

Figure 28 shows the Read operation in which the client reads the server data. Data communication by GATT is performed based on the handle information.

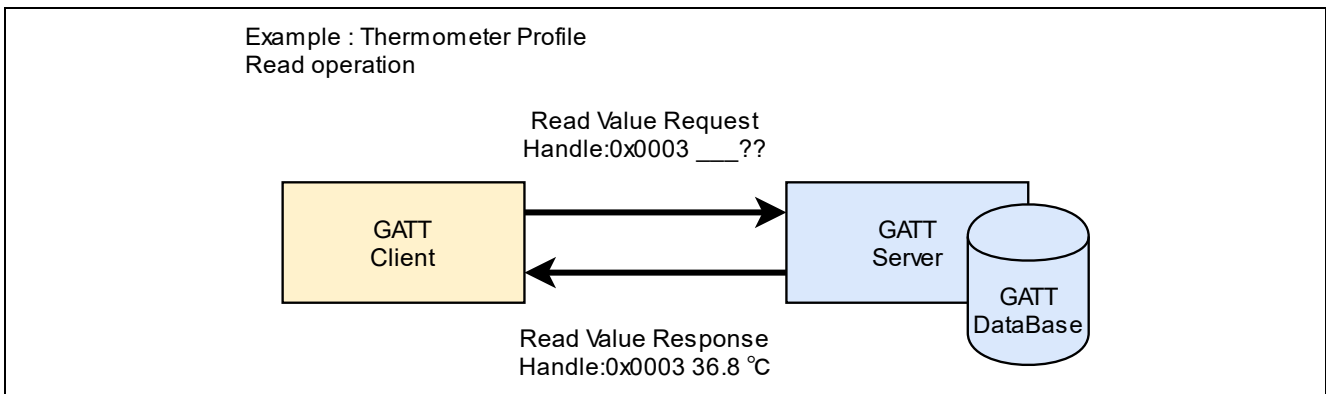
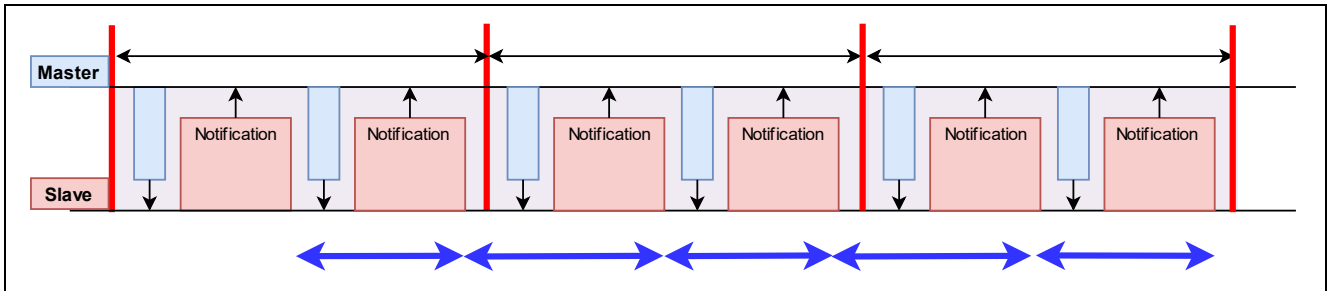


Figure 28. Read operation

**3.2.1 No response operation (Notification / Write Without Response)**

In Notification or Write Without Response operations, the next packet can be transmitted without waiting for the response. Therefore, it is possible to continuously send data by using the More Data feature. Figure 29 shows the Notification operation.

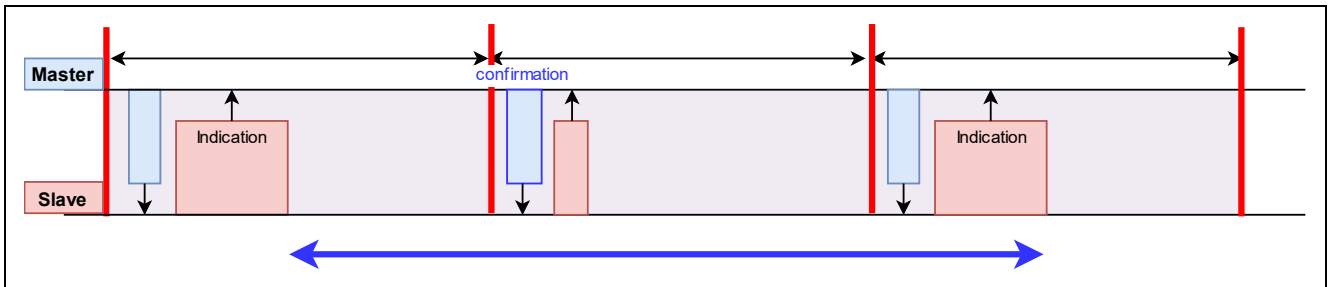


**Figure 29. Schematic diagram of Link Layer during Notification operation**

In the figure above, the slave acts as a server and performs a Notification.

**3.2.2 Response operation (Indication / Write)**

In Indication and Write operations, the next packet can be transmitted after the response. Therefore, a request to transmit the next data cannot be sent in one connection event, and it cannot be performed More Data feature. Figure 30 shows Link Layer operation for Indication. It takes twice as long as the connection interval to transmit one data packet.



**Figure 30. Schematic diagram of Link Layer during Indication operation**

In the figure above, the slave acts as a server and performs Indication.

### 3.3 Profile design by using QE for BLE

This section describes how to create profiles by using QE for BLE, using the custom throughput service used in the demo project as an example. Throughput service has characteristics shown in Table 5. The purpose of these characteristics are data transmitted and received for throughput measurements.

To open QE for BLE, select Renesas views -> Renesas QE -> R\_BLE Custom Profile RA, RE (QE) on e2studio menu bar.



Figure 31. e2studio menu

And then, following screen will open.

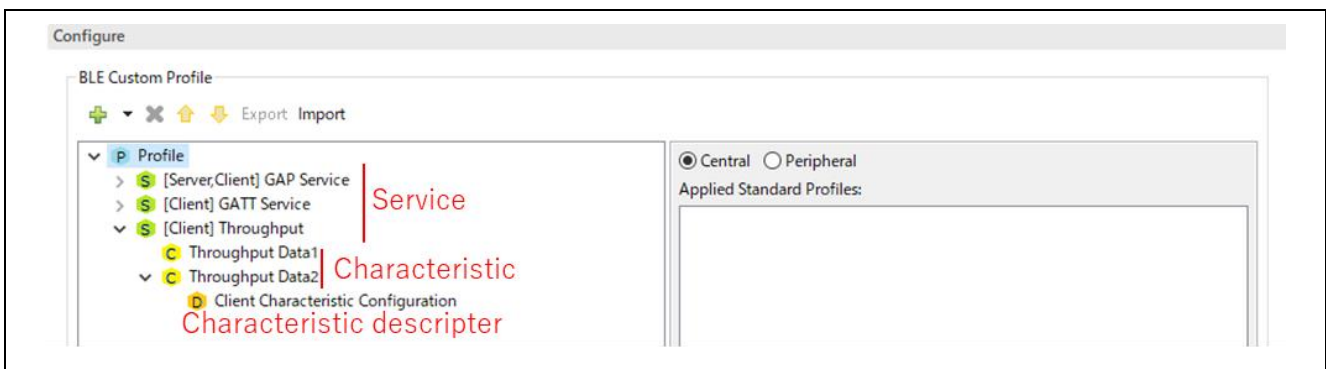
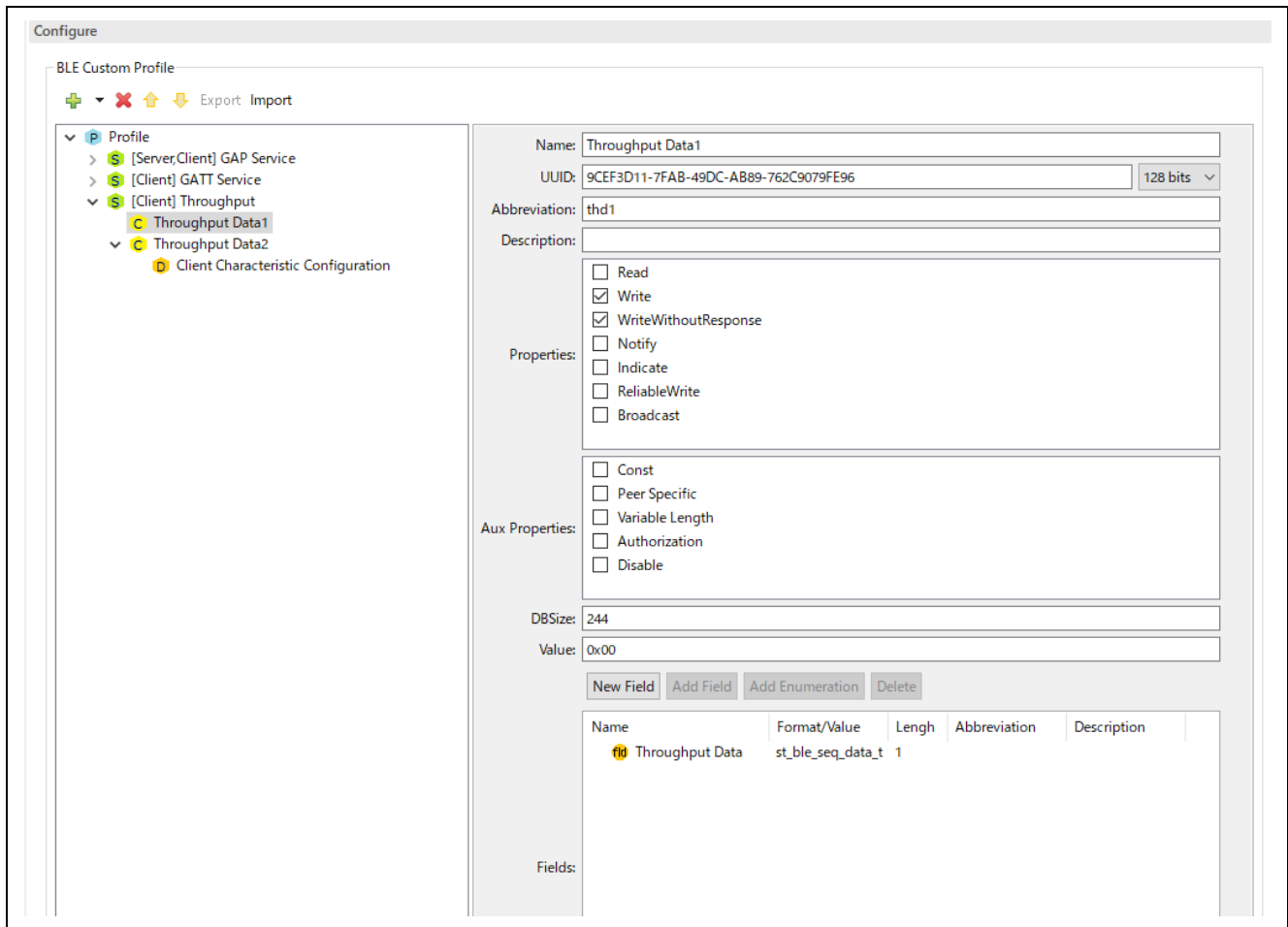


Figure 32. Profile configuration screen

Figure 33 shows the configuration screen of the Throughput Data 1 Characteristic of the throughput service.



**Figure 33. Characteristic configuration screen of Throughput Data 1 Characteristic**

It is necessary to configure following properties in above screen.

- 1) Name of characteristic, UUID, Abbreviation and check Write and Write Without Response of Properties.
- 2) Aux Properties configure data management in the GATT database. There are no items to set for the throughput service.
- 3) Set *DBSize* and Value. *DBSize* sets the number of bytes reserved for storing data on the GATT database.
- 4) Finally, set *Fields*. *Field* defines the characteristic structure handled in the application. This characteristic structure is reciprocally converted by the encode / decode functions set in the service API to packet data or GATT database data.

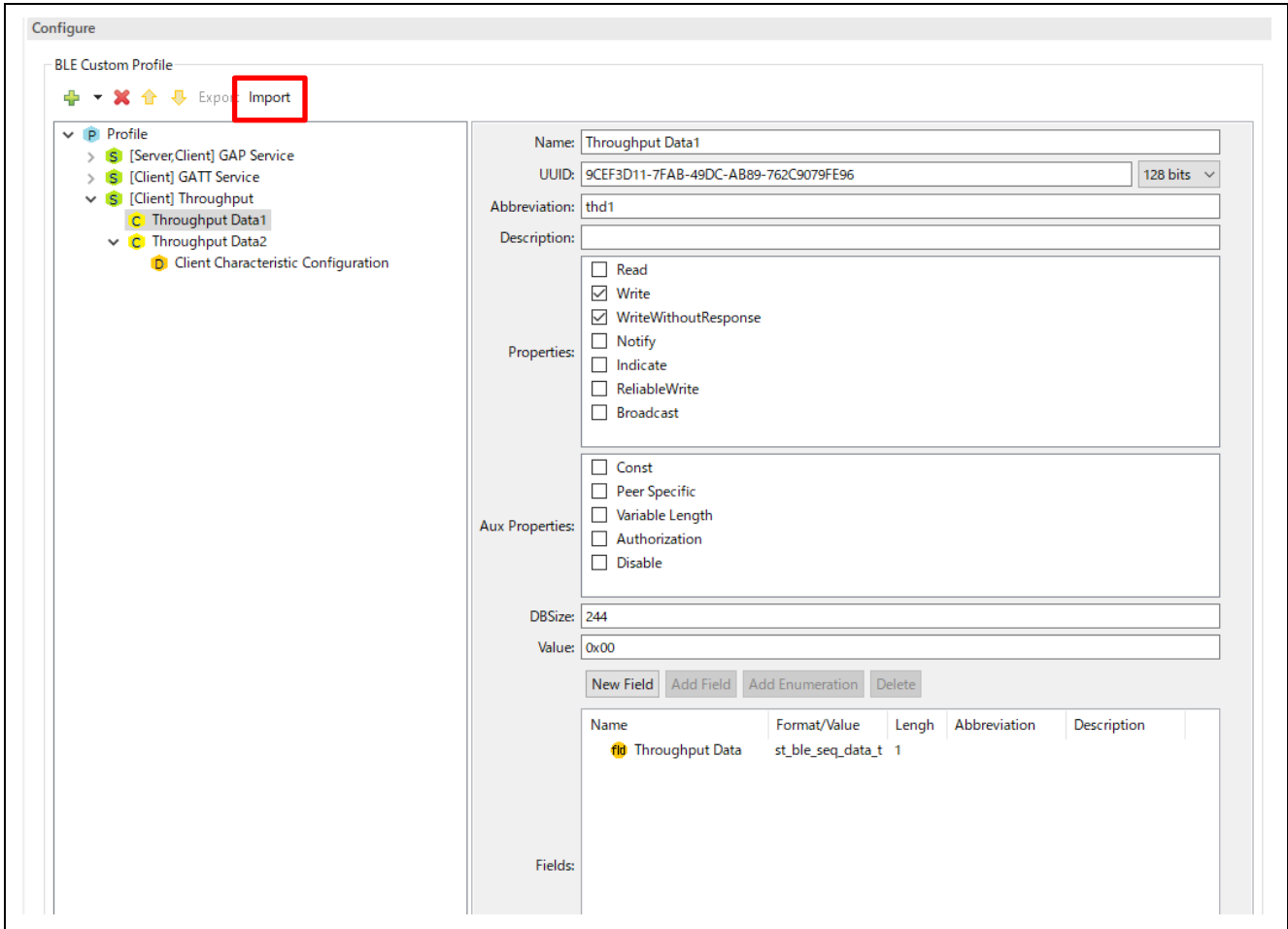
You can make Throughput Data 2 characteristic according to above procedures and Table 5.

The Throughput custom service can be re-created by importing following json files contained in this document into QE for BLE.

**Table 8. json files**

File name	GATT Role
Throughput_Server.json	Server
Throughput_Client.json	Client

When you import above json file to your own project, press “Import” button and specify json file.



**Figure 34. Import json file**

The characteristics of the throughput service in sample application use the `st_ble_seq_data_t` structure. This structure has members that mean the start address of array data and length of array data. The encode / decode functions will automatically generate by QE for BLE. Therefore, you can transmit and receive array data without implementing the encode / decode functions.

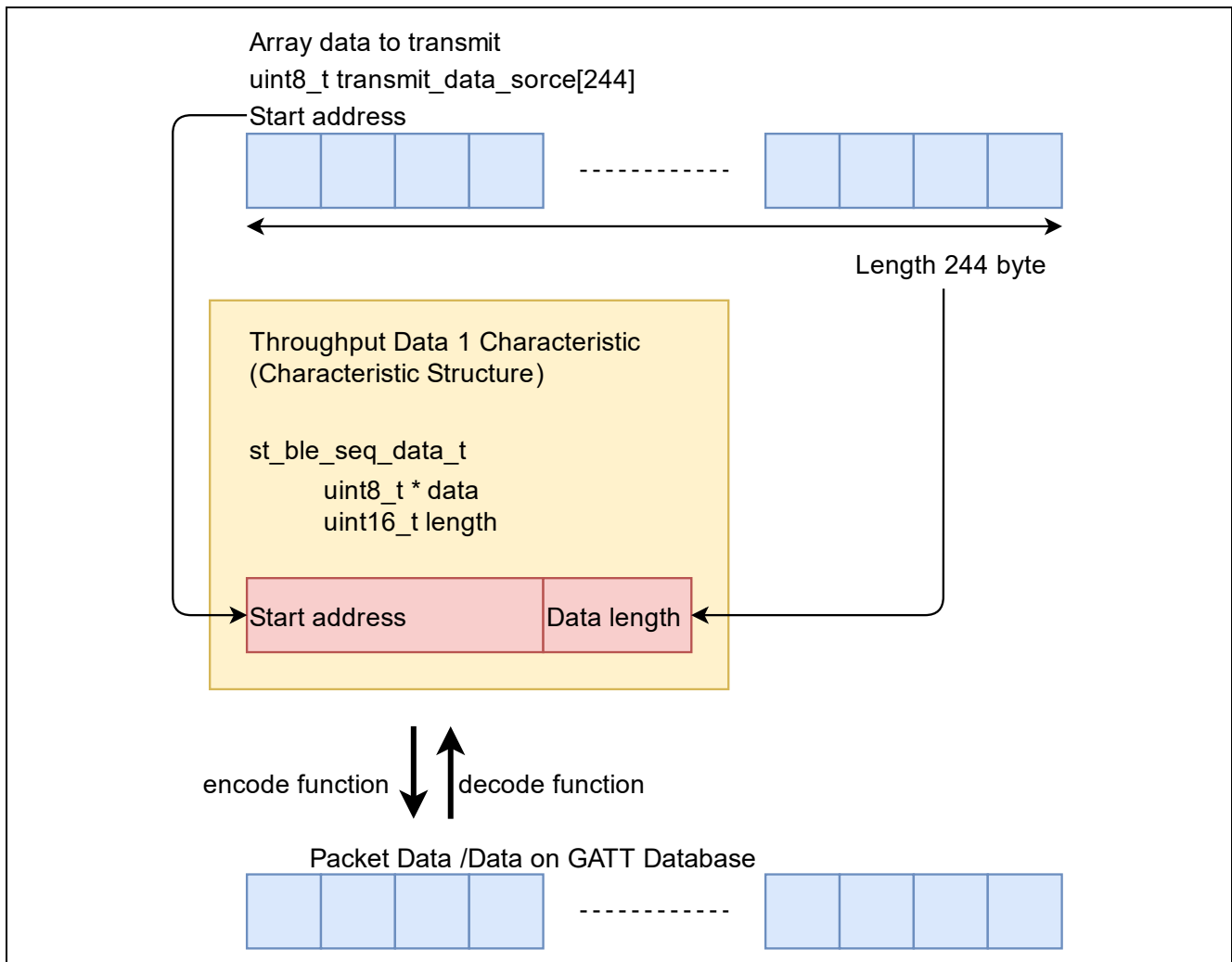


Figure 35. Transmitting array data using `st_ble_seq_data_t` structure

For details on how to develop a profile using QE for BLE, refer to "*RA4W1 Group Bluetooth Low Energy Profile Developer's Guide (R01AN6469)*".

## 4. Appendix

### 4.1 Command reference

Throughput measurement command

thc command		
Format :	thc [operation] {param}	
	Start or stop throughput measurement	
Parameters	[operation]	Start or stop throughput measurement. start : start throughput measurement
	{param}	[operation] : start notification : start notification from the server to the client. indication : start indication from the server to the client. write_without_response : start write without response from the client to the server write : start write from the client to the server.
Example	thc start notification Start notification from server to client.	



**Revision History**

Rev.	Date	Description	
		Page	Summary
1.00	June.17.2021	—	First edition issued
1.01	Dec. 28. 2022	—	Add sample application for FreeRTOS and AzureRTOS.
		5	Update Table 3.
		13, 14	Update Figure 11 and Figure 12.
		24	Add section 3.1.7.
		28	Add Table 8 and Figure 34.

## General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

### 1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity.

Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

### 2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

### 3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

### 4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

### 5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

### 6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).

### 7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

### 8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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